

MOTOROLA SEMICONDUCTOR TECHNICAL DATA

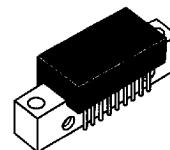
The RF Line Wideband Linear Amplifiers

. . . designed for amplifier applications in 50 to 100 ohm systems requiring wide bandwidth, low noise and low distortion. This hybrid provides excellent gain stability with temperature and linear amplification as a result of the push-pull circuit design.

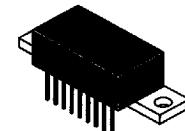
- Specified Characteristics at $V_{CC} = 15$ V, $T_C = 25^\circ\text{C}$:
 - Frequency Range — 10 to 1200 MHz
 - Output Power — 1.0 W Typ @ 1 dB Compression, $f = 900$ MHz
 - Power Gain — 15.5 dB Typ @ $f = 1000$ MHz
 - Noise Figure — 7.5 dB Typ @ $f = 500$ MHz
 - ITO — 40.5 dBm Typ @ $f = 1000$ MHz
- All Gold Metallization for Improved Reliability
- Optimized for 15 Volt Operation
- CA5915 is Optimized for 15 V Operation

**CA5915
CA5915S**

15 dB
10–1200 MHz
1.0 WATT
WIDEBAND
LINEAR AMPLIFIERS



CASE 714P, STYLE 3
(CA)
CA5915



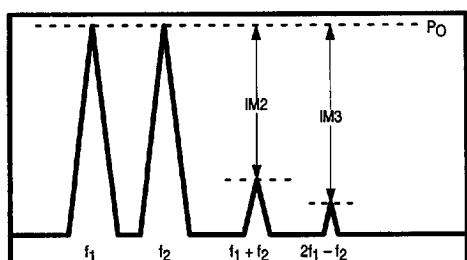
CASE 714T, STYLE 2
CA5915S

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{CC}	18	Vdc
RF Power Input	P_{in}	+20	dBm
Operating Case Temperature Range	T_C	-40 to +100	°C
Storage Temperature Range	T_{stg}	-55 to +125	°C

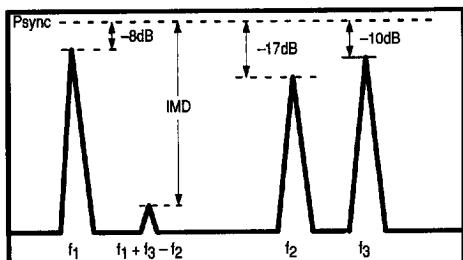
ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$, $V_{CC} = 15$ V, 50 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Supply Current	I_{CC}	—	700	760	mA
Frequency Range (3 dB Down at 10 MHz)	BW	10	—	1200	MHz
Gain Flatness ($f = 40$ –1200 MHz)	—	—	1	2	dB
Power Gain ($f = 1000$ MHz)	P_G	14.5	15.5	—	dB
Noise Figure, Broadband $f = 500$ MHz $f = 1200$ MHz	NF	— —	7.5 8.5	8.5 9.5	dB
Power Output — 1.0 dB Compression ($f = 900$ MHz)	P_o 1dB	800	1000	—	mW
Third Order Intercept (See Figure 1, $f_1 = 10$ –1200 MHz)	ITO	—	40.5	—	dBm
Input/Output VSWR $f = 40$ –900 MHz $f = 900$ –1200 MHz	VSWR	— —	— 2.6:1	2:1 —	—
Second Harmonic Distortion ($P_o = 100$ mW, $f_{2H} = 1200$ MHz)	d_{so}	—	-50	-45	dB
Intermodulation Distortion, 3 Tone (Vision Carrier = -8.0 dB, Sound Carrier = -10 dB, Sideband Signal = -17 dB, See Figure 2, $f = 860$ MHz, $P_{sync} = 200$ mW)	IMD	—	-60	—	dB
Second Order Intermodulation Distortion ($P_o = 2.75$ dBm, $f_1 = 373$ MHz, $f_2 = 450$ MHz, See Figure 1)	IM2	—	-65	-60	dB



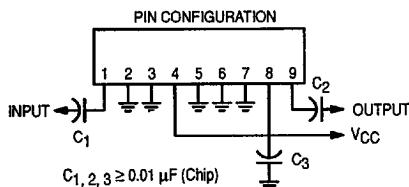
$$ITO = P_O + \frac{IM_3}{2} \quad @ \quad IM_3 > 60dB$$

Figure 1. 2-Tone Intermodulation, Test A



f1: video
f2: sideband
f3: sound

Figure 2. 3-Tone TV Intermodulation Test



**CA5915 (Case 714P-02, Style 3)
CA5915S (Case 714T-02, Style 2)**

Figure 3. External Connections